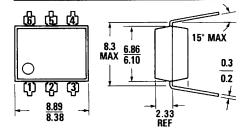
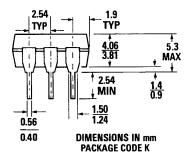


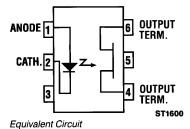
H11F1 H11F2 H11F3

PACKAGE DIMENSIONS





ST1603A



TOTAL PACKAGE

DESCRIPTION

The H11F series has a gallium-aluminum-arsenide infrared emitting diode coupled to a symmetrical bilateral silicon photodetector. The detector is electrically isolated from the input and performs like an ideal isolated FET designed for distortion-free control of low level ac and dc analog signals. The H11F series devices are mounted in dual in-line packages.

FEATURES

As a remote variable resistor—

- \leq 100 Ω to \geq 300 M Ω
- ≥99.9% linearity
- ≤15 pF shunt capacitance
- ≥100 GΩ I/O isolation resistance

As an analog switch-

- Extremely low offset voltage
- 60 V pk-pk signal capability
- No charge injection or latchup
- t_{on} , $t_{off} \leq 15 \mu s$
- Underwriters Laboratory (UL) recognized—File #E90700

APPLICATIONS

As a variable resistor-

- Isolated variable attenuator
- Automatic gain control
- Active filter fine tuning/band switching

As an analog switch-

- Isolated sample and hold circuit
- Multiplexed, optically isolated A/D conversion

ABSOLUTE MAXIMUM RATINGS

DETECTOR

Power dissipation (at 25°C ambient)	. 300 mW
Derate linearly (above 25°C ambient)	4 mW/°C
Breakdown voltage (H11F1, H11F2)	±30 V
Breakdown voltage (H11F3)	±15 V
Continuous detector current	±100 mA



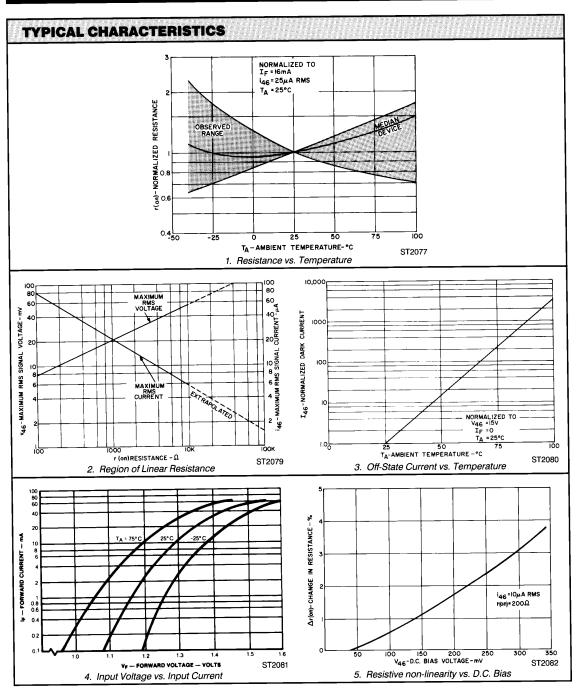
ELECTRICAL CHARACTERISTICS (T_A=25° Unless Otherwise Specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE Forward voltage	V_{F}		1.1	1.75	٧	I _F =16 mA
Reverse current	I _B			10	μA	V _R =5 V
Capacitance	C,		50		pF	V=0, f=1 MHz
OUTPUT DETECTOR (Ei Breakdown voltage (H11F1, H11F2)	ther polarit	y) 30			V	$I_c=10 \mu A, I_F=0$
(H11F3)	BV ₄₆	15			V	$I_c=10 \mu A, I_f=0$
Off-state dark current	Ī ₄₆			50	nA	$V_{46} = 15 \text{ V}, I_F = 0$
	I ₄₆			50	μΑ	V ₄₆ =15 V, I _F =0, T _A =100°C
Off-state resistance	r ₄₆	300			MΩ	V ₄₆ =15 V, I _F =0
Capacitance	C ₄₆			15	pF	$V_{46}=0$, $I_{E}=0$, $f=1$ MHz

CHARACTERISTIC		SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
On-state resistance	(H11F1)	r ₄₆			200	Ω	$I_F = 16 \text{ mA}, I_{46} = 100 \mu\text{A}$
	(H11F2)	r ₄₆			330	Ω	I _F =16 mA, I ₄₆ =100 μA
	(H11F3)	r ₄₆			470	Ω	$I_F = 16 \text{ mA}, I_{46} = 100 \mu\text{A}$
On-state resistance	(H11F1)	r ₆₄			200	Ω	$I_F = 16 \text{ mA}, I_{64} = 100 \mu\text{A}$
	(H11F2)	r ₆₄			330	Ω	$I_F = 16 \text{ mA}, I_{64} = 100 \mu\text{A}$
	(H11F3)	r ₆₄		_	470	Ω	$I_F = 16 \text{ mA}, I_{64} = 100 \mu\text{A}$
Turn-on time	- 45	t _{on}			25	μS	I_F =16 mA, V_{46} =5 V, R_L =50 Ω
Turn-off time		t _{off}			25	<u>μ</u> s	I_F =16 mA, V_{46} =5 V, R_L =50 Ω
Resistance, non-linearity and	asymmetry				0.1	%	I _F =16 mA, R _L =50 Ω, V ₄₆ =5 V

ISOLATION CHARACTE	RISTICS			
Surge isolation voltage	V _{iso}	7500	V _{Peak}	1 Minute
Surge isolation voltage	V _{ISO}	5300	V _{RMS}	1 Minute
Isolation resistance (input to output)		1011	Ω	V ₁₀ =0, f=1 MHz
Input to output capacitance			2 pF	V₁₀=0, f=1 MHz



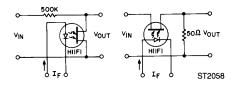




TYPICAL APPLICATIONS

AS A VARIABLE RESISTOR

ISOLATED VARIABLE ATTENUATORS



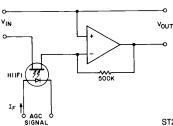
LOW FREQUENCY

@ IOKHZ DYNAMIC RANGE ≈ 70db FOR O≤IF≤30mA

HIGH FREQUENCY @ IMHz DYNAMIC RANGE ≈ 50db FOR 0 ≤ IF ≤ 30mA

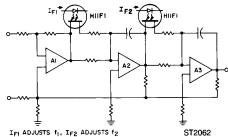
Distortion free attenuation of low level A.C. signals is accomplished by varying the IRED current, IF. Note the wide dynamic range and absence of coupling capacitors; D.C. level shifting or parasitic feedback to the controlling function.

AUTOMATIC GAIN CONTROL



This simple circuit provides over 70db of stable gain control for an AGC signal range of from 0 to 30mA. This basic circuit can be used to provide programmable fade and attack for electronic music.

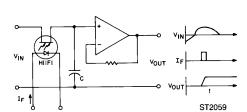
ACTIVE FILTER FINE TUNING/BAND SWITCHING



The linearity of resistance and the low offset voltage of the H11F allows the remote tuning or band-switching of active filters without switching glitches or distortion. This schematic illustrates the concept, with current to the H11F1 IRED's controlling the filter's transfer characteristic.

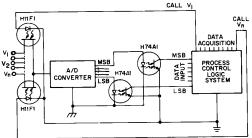
AS AN ANALOG SIGNAL SWITCH

ISOLATED SAMPLE AND HOLD CIRCUIT



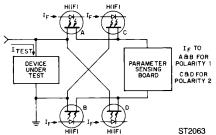
Accuracy and range are improved over conventional FET switches because the H11F has no charge injection from the control signal. The H11F also provides switching of either polarity input signal up to 30V magnitude.

MULTIPLEXED, OPTICALLY-ISOLATED A/D CONVERSION



The optical isolation, linearity and low offset voltage of the H11F allows the remote multiplexing of low level analog signals from such transducers as thermocouplers, Hall effect devices, strain gauges, etc. to a single A/D converter.

TEST EQUIPMENT - KELVIN CONTACT POLARITY



In many test equipment designs the auto polarity function uses reed relay contacts to switch the Kelvin Contact polarity. These reeds are normally one of the highest maintenance cost items due to sticking contacts and mechanical problems. The totally solid-state H11F eliminates these troubles while providing fas-



PHOTOFET OPTOCOUPLERS

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.